

TECHNICAL DATA DATA SHEET 5365, REV. -

HERMETIC FAST RECOVERY RECTIFIER HIGH VOLTAGE

Features:

- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- Very High Surge Capacity
- Very suitable for medium to high frequency applications (upto 40 kHz)
- Soft Reverse Recovery at Low and High Temperature
- Trr guaranteed lower than 0.5µsec
- For ceramic seals use part number prefix SHDC
- Different Lead-bend options available
- Electrically / Mechanically Stable during and after Packaging

Maximum Ratings:

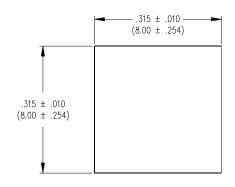
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	1200	V
Max. Average Forward	I _{F(AV)}	50% duty cycle, rectangular wave	32	Α
Current	, ,	form, $T_C = 65 ^{\circ}C$		
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 msec, sine pulse	300	Α
Thermal Resistance	Z_{TH}	T _C = 25 °C	0.85	°C / W
Max. Junction Temperature	TJ	-	- 55 to + 150	°C
Max. Storage Temperature	T _{stg}	-	- 55 to + 150	°C

Electrical Characteristics:

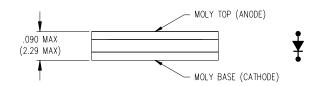
Characteristics	Symbol	Condition	Тур.	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 9A, Pulse, T _J = 25 °C	1.15	1.25	V
		@ 32A, Pulse, T _J = 25 °C	1.40	1.55	
	V_{F2}	@ 9A, Pulse, T _J = 125 °C	-	1.18	V
		@ 32A, Pulse, T _J = 125 °C		1.45	
Max. Reverse Current	I _{R1}	@V _R = 1200V, Pulse, T _J = 25 °C	2	50	μΑ
	I _{R2}	@V _R = 1200V, Pulse, T _J = 125 °C	-	500	μΑ
Reverse Recovery Time	T_RR	$I_F = 0.5A$; $I_{RM} = 1A$, $I_{RR} = 0.25A$	0.3	0.5	μS
		T _J = 25 °C			
Capacitance	CJ	$V_R = 5V$, $f = 1MHz$, $V_{SIG} = 1V$	-	150	рF

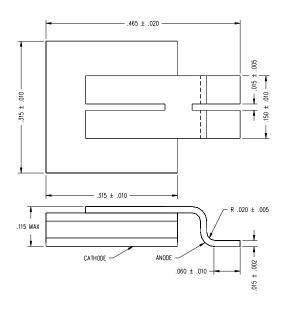
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MECHANICAL DIMENSIONS: In Inches / mm



SHD-2 High Profile





SHD-2B High Profile

PINOUT TABLE

SHD375589

TYPE	PIN 1 (Base)	Pin 2
SINGLE RECTIFIER	CATHODE	ANODE
in a Surface Mount Package		



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